

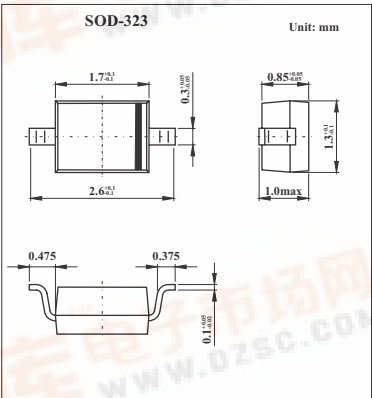
SMD Type

Diodes

LOW VOLTAGE HIGH SPEED SWITCHING
1SS357

■ Features

- Low forward voltage : $V_{F(3)} = 0.54\text{ V(Typ)}$
- Low resistance current : $I_R = 5\text{ }\mu\text{ A (Max)}$
- Small package: :SC-70



■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Maximum (peak) reverse voltage	V_{RM}	85	V
Reverse voltage	V_R	80	V
Maximum (peak) forward current	I_{FM}	200	mA
Average forward current	I_O	100	mA
Surge current (10 ms)	I_{FSM}	1	A
Power dissipation	P	200(*)	mW
Junction Temperature	T_J	125	$^\circ\text{C}$
Storage Temperature range	T_{stg}	-55 + 125	$^\circ\text{C}$

(*) Mounted on a glass epoxy circuit board of 20 * 20 mm, pad dimension of 4 * 4 mm.

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Forward voltage	$V_{F(1)}$	$I_F = 1\text{ mA}$		0.28		V
	$V_{F(2)}$	$I_F = 10\text{ mA}$		0.36		
	$V_{F(3)}$	$I_F = 100\text{ mA}$		0.54	0.6	
Reverse current	I_R	$V_R = 40\text{ V}$			5	$\mu\text{ A}$
Total capacitance	C_t	$V_R = 0, f = 1.0\text{ MHz}$		18	25	pF

■ Marking

Marking	S3
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